RT3P55M

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION

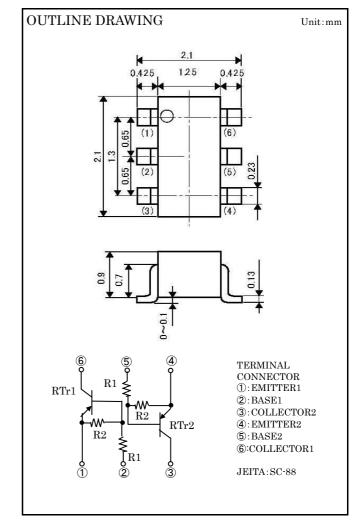
RT3P55M is compound transistor built with two RT1P144 chips in SC-88 package.

FEATURE

Silicon epitaxial type Each transistor elements are independent. Mini package for easy mounting

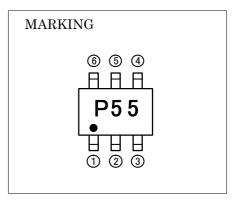
APPLICATION

Inverted circuit, switching circuit, interface circuit, driver circuit



MAXIMUM RATING (Ta=25°C) (RTr1, RTr2)

| SYMBOL | PARAMETER | RATING | UNIT |
|-----------------------------|---------------------------------------|----------|------|
| Vcbo | Collector to Base voltage | -50 | V |
| Vebo | Emitter to Base voltage | -6 | V |
| VCEO | Collector to Emitter voltage | -50 | V |
| Vin | Input voltage | -40 | V |
| IC | Collector current | -100 | mA |
| ICM | Peak Collector current | -200 | mA |
| Pc | Collector dissipation(Total, Ta=25°C) | 150 | mW |
| Tj | Junction temperature | +150 | °C |
| $\mathrm{T}_{\mathrm{stg}}$ | Storage temperature | -55~+150 | °C |



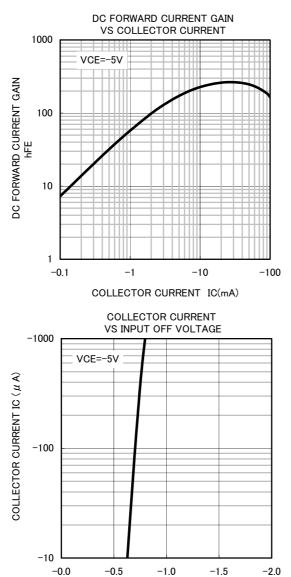
RT3P55M

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

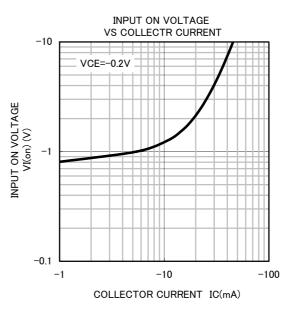
ELECTRICAL CHARACTERISTICS (Ta=25°C) (RTr1, RTr2)

| Symbol | Parameter | Test conditions | Limits | | | Unit |
|------------------|---|---|--------|------|------|------|
| | | | Min | Тур | Max | Unit |
| V(BR)CEO | Collector to Emitter break down voltage | I _с =-100µА, R _{BE} =∞ | -50 | — | — | V |
| Ісво | Collector cut off current | V_{CB} =-50V, I $_{E}$ =0 | - | — | -0.1 | μΑ |
| hFE | DC forward current gain | V _{CE} =-5V, I c=-5mA | 50 | — | _ | - |
| VCE(sat) | Collector to Emitter saturation voltage | I _c =-10mA, I _b =-0.5mA | - | -0.1 | -0.3 | V |
| VI(ON) | Input on voltage | Vce=-0.2V, I c=-5mA | - | -1.0 | -1.8 | V |
| VI(OFF) | Input off voltage | Vce=-5V, I c=-100µА | -0.4 | -0.7 | - | V |
| R1 | Input resistor | | 7 | 10 | 13 | KΩ |
| R_2/R_1 | Resistor ratio | | 4.2 | 4.7 | 5.1 | - |
| f_{T} | Gain band width product | V_{CE} =-6V, I _E =10mA | _ | 150 | — | MHz |

TYPICAL CHARACTERISTICS (RTr1,RTr2)



INPUT OFF VOLTAGE VI(off) (V)





6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

Keep safety first in your circuit designs!

ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

Notes regarding these materials

These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging

Customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party. ISAHAYA Flectronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials. •All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed backing. hereir

ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these

materials.

If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to be export control laws and regulations of Japan and/or the country of destination is prohibited. •Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these

materials or the products contained therein.